

12FU

DUAL PENTODE

8BM11

Duodecar type used as if amplifier in television receivers. Unit No.1 is a semiremote-cutoff pentode, and unit No. 2 is a sharp-cutoff pentode. Outlines section, 8B; requires duodecar 12-contact socket. Heater: volts (ac/dc), 8.4; amperes, 0.45; maximum heater-cathode volts, ± 200 peak, 100 average.

Class A₁ Amplifier

MAXIMUM RATINGS (Design-Maximum Values)

Plate Voltage	160
Grid-No.3 (Suppressor-Grid) Voltage	0
Grid-No.2 (Screen-Grid) Voltage	160
Grid-No.1 (Control-Grid) Voltage, Positive-bias value	0
Plate Dissipation	2.2
Grid-No.2 Input	0.55

Unit No.1 Unit No.2

160	160	volts
0	0	volts
160	160	volts
0	0	volts
2.2	2.2	watts
0.55	0.55	watt

CHARACTERISTICS

Plate Supply Voltage	125
Grid No.3	Connected to cathode at socket
Grid-No.2 Voltage	125
Cathode-Bias Resistor	56
Plate Resistance (Approx.)	220000
Transconductance	8300
Plate Current	14
Grid-No.2 Current	3.6
Grid-No.1 Voltage (Approx.) for plate current of 20 μ A	—
Grid-No.1 Voltage (Approx.) for transconductance of 50 μ mho	—16.5

125	125	volts
125	125	volts
56	120	ohms
220000	300000	ohms
8300	8500	μ mhos
14	9	mA
3.6	2.5	mA
—	—5.5	volts
—16.5	—	volts

MAXIMUM CIRCUIT VALUES

Grid-No.1-Circuit Resistance, for cathode-bias operation	1
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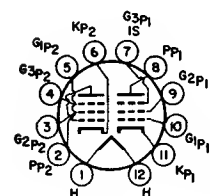
0.25	megohm
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Refer to type 6BN8.

8BN8

Refer to type 6BQ5.

8BQ5



12DM

SEMIREMOTE-CUTOFF
DUAL PENTODE

8BQ11

11BQ11

Duodecar type used as intermediate-frequency amplifier in television receivers. Outlines section, 8B; requires duodecar 12-contact socket. Type 11BQ11 is identical with type 8BQ11 except for heater ratings.

Heater Voltage (ac/dc)	8.4
Heater Current	0.6
Heater Warm-up Time (Average)	11
Heater-Cathode Voltage:	
Peak value	± 200 max
Average value	100 max

8BQ11	11BQ11	volts
8.4	11.2	ampere
0.6	0.45	seconds
11	11	
± 200 max	± 200 max	volts
100 max	100 max	volts

Direct Interelectrode Capacitances:

Grid No.1 to Plate	0.022
Grid No.1 to Cathode, Heater, Grid No.2, Grid No.3, and Internal Shield	10
Plate to Cathode, Heater, Grid No.2, Grid No.3, and Internal Shield	2.8
Grid No.1 to Cathode, Heater, Grid No.2, Grid No.3, Grid No.3 of Unit No.1, and Internal Shield	—
Plate to Cathode, Heater, Grid No.2, Grid No.3, Grid No.3 of Unit No.1, and Internal Shield	—

Unit No.1	Unit No.2	pF
0.022	0.024	pF
10	—	pF
2.8	—	pF
—	11	pF
—	2.8	pF

Plate of Unit No.1 to Plate of Unit No.2	0.015	pF
Grid No.1 of Unit No.1 to Plate of Unit No.2	0.002	pF
Grid No.1 of Unit No.2 to Plate of Unit No.1	0.008	pF
Grid No.1 of Unit No.1 to Grid No.1 of Unit No.2	0.002	pF

Class A₁ Amplifier**MAXIMUM RATINGS (Design-Maximum Values)**

	Unit No.1	Unit No.2	
Plate Voltage	330	330	volts
Grid-No.3 (Suppressor-Grid) Voltage	0	0	volts
Grid-No.2 (Screen-Grid) Supply Voltage	330	330	volts
Grid-No.2 Voltage	See curve	page 98	
Grid-No.1 (Control-Grid) Voltage, Positive-bias value	0	0	volts
Plate Dissipation	3.1	3.1	watts
Grid-No.2 Input:	0.65	0.65	watt
For grid-No.2 voltages up to 165 volts	See curve	page 98	
For grid-No.2 voltages between 165 and 330 volts			

CHARACTERISTICS

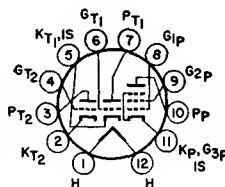
Plate Supply Voltage	125	125	volts
Grid-No.3	Connected to cathode at socket		
Grid-No.2 Voltage	125	125	volts
Cathode-Bias Resistor	56	56	ohms
Plate Resistance (Approx.)	0.2	0.2	megohm
Transconductance	10500	13000	μmhos
Plate Current	11	11	mA
Grid-No.2 Current	3.5	3.8	mA
Grid-No.1 Voltage (Approx.) for plate current of 20 μA	—	—3	volts
Grid-No.1 Voltage (Approx.) for transconductance of 50 μmho	—15	—	volts

MAXIMUM CIRCUIT VALUES

Grid-No.1-Circuit Resistance, for cathode-bias operation	1	0.25	megohm
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8BU11**MEDIUM-MU TWIN TRIODE—
SHARP-CUTOFF PENTODE**

Duodecar type used in television receiver applications. Outlines section, 8C; requires duodecar 12-contact socket. Heater: volts (ac/dc), 7.8; amperes, 0.6; warm-up time, 11 seconds, maximum heater-cathode volts, ±200 peak, 100 average.

**12FP****Class A₁ Amplifier****MAXIMUM RATINGS (Design-Maximum Values)**

	Pentode Unit	Each Triode Unit	
Plate Voltage	330	330	volts
Grid-No.2 (Screen-Grid) Supply Voltage	330	—	volts
Grid-No.2 Voltage	See curve	page 98	
Grid-No.1 (Control-Grid) Voltage, Positive-bias value	0	0	volts
Plate Dissipation	2.5	1.8	watts
Grid-No.2 Input:	0.55	—	watt
For grid-No.2 voltages up to 165 volts	See curve	page 98	
For grid-No.2 voltages between 165 and 330 volts			

CHARACTERISTICS

Plate Supply Voltage	125	125	volts
Grid-No.2 Voltage	125	—	volts
Grid-No.1 Voltage	—1	—	volts
Cathode-Bias Resistor	—	68	ohms
Amplification Factor	—	43	
Plate Resistance (Approx.)	200000	50000	ohms
Transconductance	7500	8600	μmhos
Plate Current	12	13.5	mA
Grid-No.2 Current	4	—	mA
Grid Voltage (Approx.) for plate current of 100 μA	—	—8	volts
Grid-No.1 Voltage (Approx.) for plate current of 30 μA	—8	—	volts

MAXIMUM CIRCUIT VALUES

Grid-No.1-Circuit Resistance:			
For fixed-bias operation	0.5	0.5	megohm
For cathode-bias operation	1	1	megohm